

**TUNNEL OXIDE PASSIVATING ELECTRON CONTACTS AS FULL-AREA REAR EMITTER OF  
HIGH-EFFICIENCY P-TYPE SILICON SOLAR CELLS**

Armin Richter<sup>a</sup>, Jan Benick<sup>a</sup>, Ralph Müller<sup>a,b</sup>, Frank Feldmann<sup>a,b</sup>, Christian Reichel<sup>a</sup>,  
Martin Hermle<sup>a</sup>, Stefan W. Glunz<sup>a,b</sup>

<sup>a</sup> Fraunhofer Institute for Solar Energy Systems (ISE), Heidenhofstrasse 2, 79110 Freiburg, Germany

<sup>b</sup> Department of Sustainable Systems Engineering, Albert Ludwig University of Freiburg,  
Georges-Köhler-Allee 103, D-79110 Freiburg, Germany

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